

Complementary NPN-PNP Power Bipolar Transistors

NJW0281G (NPN), NJW0302G (PNP)

These complementary devices are lower power versions of the popular NJW3281G and NJW1302G audio output transistors. With superior gain linearity and safe operating area performance, these transistors are ideal for high fidelity audio amplifier output stages and other linear applications.

Features

- Exceptional Safe Operating Area
- NPN/PNP Gain Matching within 10% from 50 mA to 3 A
- Excellent Gain Linearity
- High BVCEO
- High Frequency
- These Devices are Pb-Free and are RoHS Compliant

Benefits

- Reliable Performance at Higher Powers
- Symmetrical Characteristics in Complementary Configurations
- Accurate Reproduction of Input Signal
- Greater Dynamic Range
- High Amplifier Bandwidth

Applications

- High-End Consumer Audio Products
 - ◆ Home Amplifiers
 - ◆ Home Receivers
- Professional Audio Amplifiers
 - ◆ Theater and Stadium Sound Systems
 - ◆ Public Address Systems (PAs)

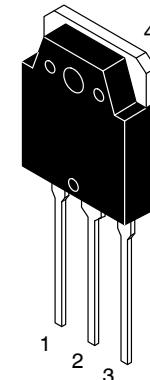
MAXIMUM RATINGS

Symbol	Rating	Value	Unit
V_{CEO}	Collector-Emitter Voltage	250	Vdc
V_{CBO}	Collector-Base Voltage	250	Vdc
V_{EBO}	Emitter-Base Voltage	5.0	Vdc
V_{CEX}	Collector-Emitter Voltage - 1.5 V	250	Vdc
I_C	Collector Current - Continuous	15	Adc
I_{CM}	Collector Current - Peak (Note 1)	30	Adc
I_B	Base Current - Continuous	1.5	Adc
P_D	Total Power Dissipation @ $T_C = 25^\circ\text{C}$	150	Watts
T_J, T_{stg}	Operating and Storage Junction Temperature Range	– 65 to +150	°C

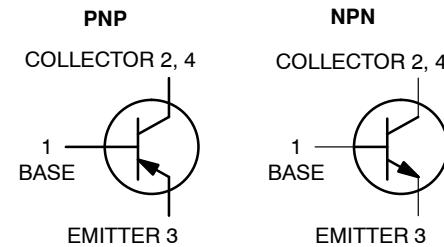
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Pulse Test: Pulse Width = 5.0 ms, Duty Cycle < 10%.

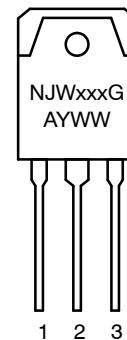
15 AMPERES
COMPLEMENTARY SILICON
POWER TRANSISTORS
250 VOLTS, 150 WATTS



TO-3P
CASE 340AB
STYLES 1,2,3



MARKING DIAGRAM



xxxx = 0281 or 0302
G = Pb-Free Package
A = Assembly Location
Y = Year
WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
NJW0281G	TO-3P (Pb-Free)	30 Units/Rail
NJW0302G	TO-3P (Pb-Free)	30 Units/Rail

NJW0281G (NPN), NJW0302G (PNP)

THERMAL CHARACTERISTICS

Symbol	Characteristic	Value	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	0.83	°C/W

ELECTRICAL CHARACTERISTICS ($T_C = 25$ °C unless otherwise noted)

Symbol	Characteristic	Min	Max	Unit
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OFF CHARACTERISTICS

$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage ($I_C = 30$ mA, $I_B = 0$)	250	–	V
I_{CBO}	Collector Cutoff Current ($V_{CB} = 250$ V, $I_E = 0$)	–	10	μA
I_{EBO}	Emitter Cutoff Current ($V_{EB} = 5.0$ V, $I_C = 0$)	–	5.0	μA

ON CHARACTERISTICS

h_{FE}	DC Current Gain ($I_C = 0.5$ A, $V_{CE} = 5.0$ V) ($I_C = 1.0$ A, $V_{CE} = 5.0$ V) ($I_C = 3.0$ A, $V_{CE} = 5.0$ V)	75	150	–
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage ($I_C = 5.0$ A, $I_B = 0.5$ A)	–	1.0	V
$V_{BE(on)}$	Base-Emitter On Voltage ($I_C = 5.0$ A, $V_{CE} = 5.0$ V)	–	1.2	V

DYNAMIC CHARACTERISTICS

f_T	Current-Gain - Bandwidth Product ($I_C = 1.0$ A, $V_{CE} = 5.0$ V, $f_{test} = 1.0$ MHz)	30	–	MHz
C_{ob}	Output Capacitance ($V_{CB} = 10$ V, $I_E = 0$, $f_{test} = 1.0$ MHz)	–	400	pF

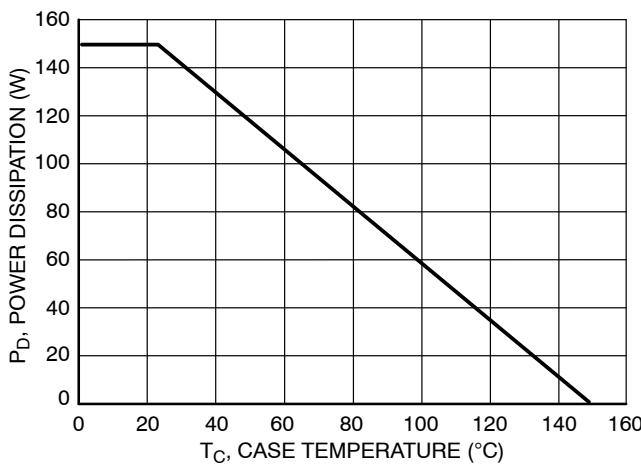


Figure 1. Power Derating

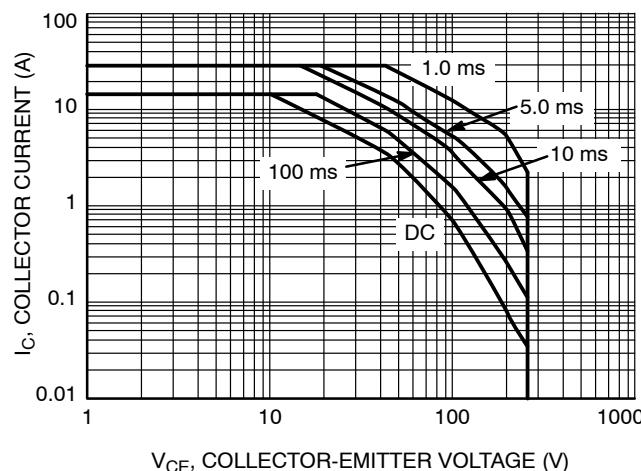


Figure 2. Safe Operating Area

NJW0281G (NPN), NJW0302G (PNP)

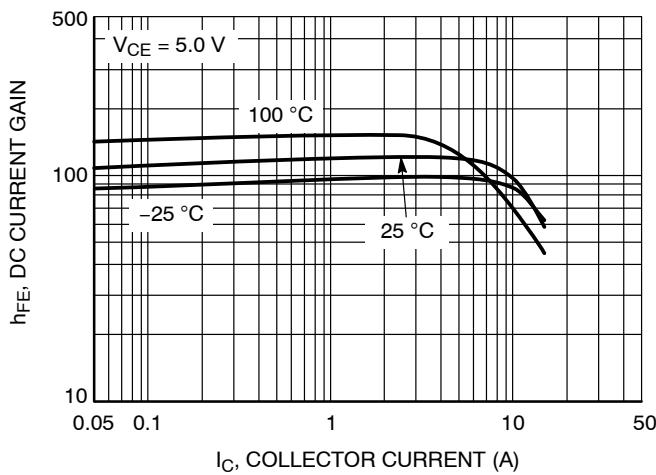


Figure 3. NJW0281G DC Current Gain

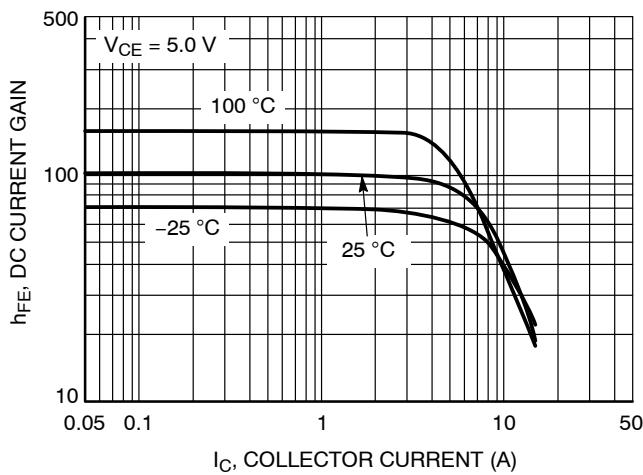


Figure 4. NJW0302G DC Current Gain

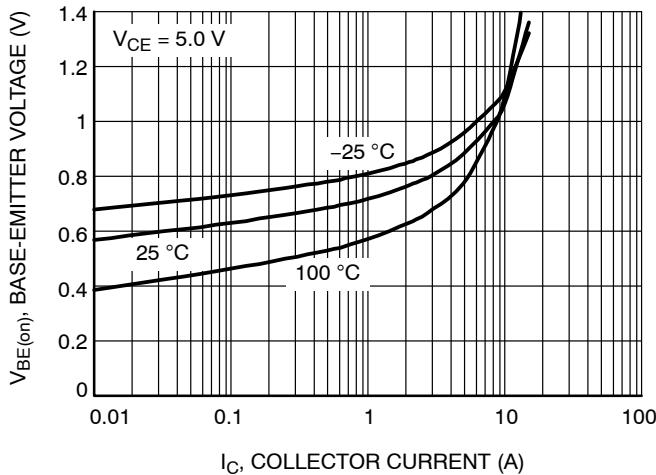


Figure 5. NJW0281G Base-Emitter Voltage

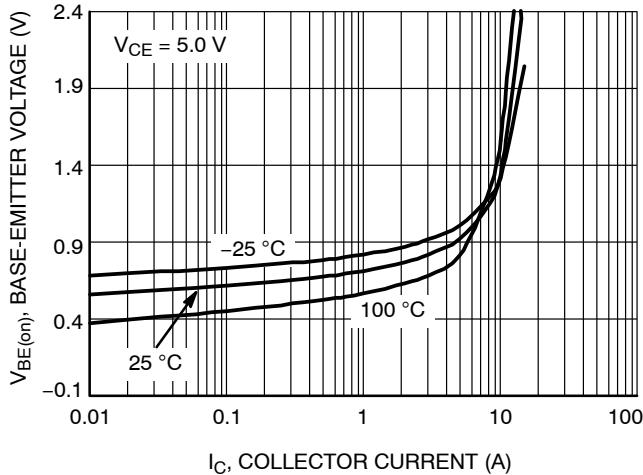


Figure 6. NJW0302G Base-Emitter Voltage

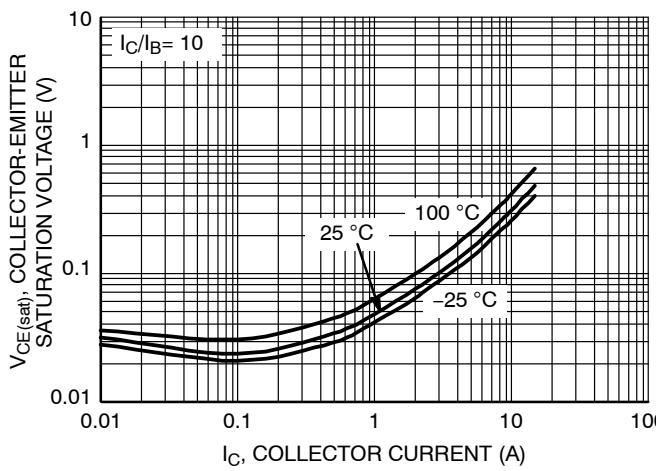


Figure 7. NJW0281G Saturation Voltage

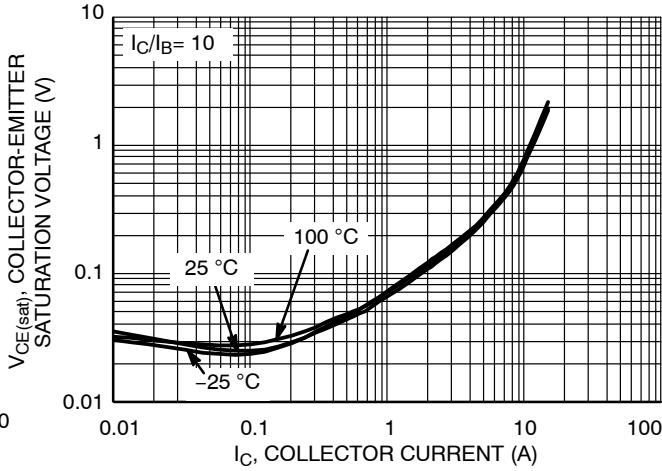


Figure 8. NJW0302G Saturation Voltage

NJW0281G (NPN), NJW0302G (PNP)

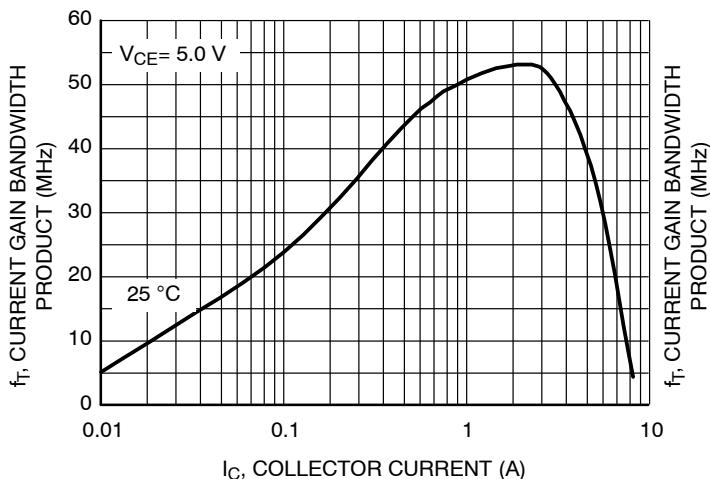


Figure 9. NJW0281G Current Gain Bandwidth Product

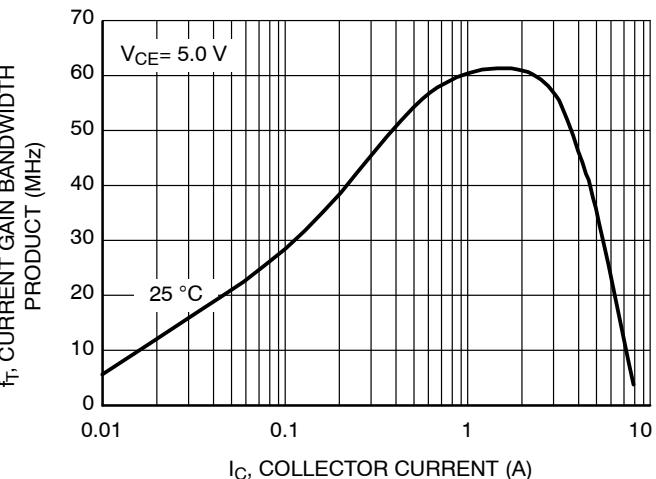


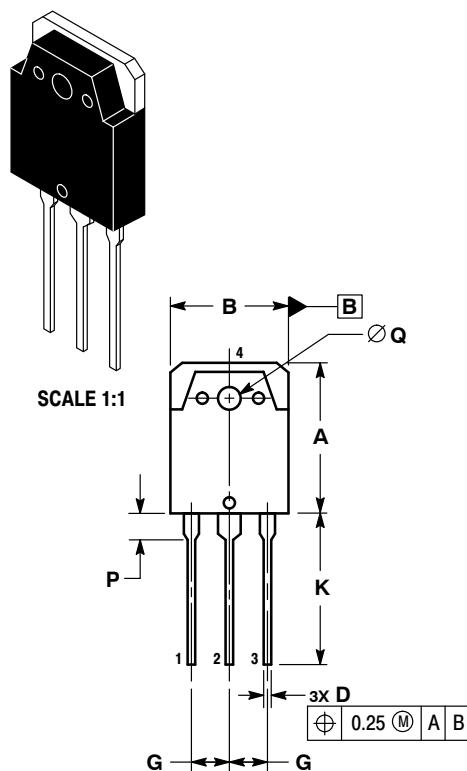
Figure 10. NJW0302G Current Gain Bandwidth Product

NJW0281G (NPN), NJW0302G (PNP)

REVISION HISTORY

Revision	Description of Changes	Date
2	Rebranded the Data Sheet to onsemi format.	6/26/2025

This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.



TO-3P-3LD
CASE 340AB
ISSUE A

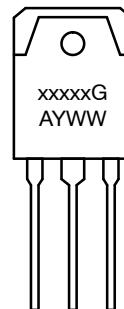
DATE 30 OCT 2007

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION B APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30mm FROM THE TERMINAL TIP.
4. DIMENSION A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

DIM	MILLIMETERS		
	MIN	NOM	MAX
A	19.70	19.90	20.10
B	15.40	15.60	15.80
C	4.60	4.80	5.00
D	0.80	1.00	1.20
E	1.45	1.50	1.65
F	1.80	2.00	2.20
G	5.45 BSC		
H	1.20	1.40	1.60
J	0.55	0.60	0.75
K	19.80	20.00	20.20
L	18.50	18.70	18.90
P	3.30	3.50	3.70
Q	3.10	3.20	3.50
U	5.00 REF		
W	2.80	3.00	3.20

GENERIC MARKING
DIAGRAM*



xxxxx = Specific Device Code
G = Pb-Free Package
A = Assembly Location
Y = Year
WW = Work Week

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present.

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